

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	585	(257/413).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/24 14:43
L2	596	(257/E29.156).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/24 14:43
L3	265	(DARC ARC (antireflection antireflective anti adj (reflection reflective)) adj (layer film coating)) and gate adj (oxide dielectric) and photoresist and (SiON SiNO silicon adj (oxynitride oxime) "SiNO:H" "SiON:H") and (SiN silicon adj nitride) and (anneal annealed)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/24 14:43
L4	862	(DARC ARC (antireflection antireflective anti adj (reflection reflective)) adj (layer film coating)) and gate adj (oxide dielectric) and photoresist and (SiON SiNO silicon adj (oxynitride oxime) "SiNO:H" "SiON:H") and (SiN silicon adj nitride)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/24 14:43